NSN 5961-01-130-7579

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-130-7579 **Inclosure Material:** Metal **Overall Length:** 0.621 inches **Overall Height:** 0.065 inches **Overall Width:** 0.124 inches **Mounting Method:** Press fit **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 255.0 reverse voltage, peak **Current Rating Per Characteristic:** 100.00 nanoamperes forward current, average peak **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector absolute **Capacitance Rating In Picofarads:** 0.65 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 13499-922-6510 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 ribbon and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**